



Attorney Docket No.: SEL 139 DIV

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
Shunpei Yamazaki et al. )  
Serial No.: 09/808,162 )  
Filed: March 13, 2001 )  
For: Method For Fabricating A )  
Semiconductor Device )

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Commissioner for Patents  
Washington D.C. 20231

PRELIMINARY AMENDMENT

Dear Sir:

In the specification, on page 1, delete the cross reference to the related application and insert the following:

CROSS REFERENCE TO RELATED APPLICATION

This application is a continuation of copending U.S. Application Serial No. 09/386,782 filed on August 31, 1999.

In the Claims:

Please amend claims 1-3.

1. (Amended) A method of fabricating a semiconductor device, said method comprising the steps of:

92 preparing a single crystal semiconductor substrate having a main surface of a {110} surface;